M icroscopic mechanisms of dephasing due to electron-electron interactions

R.Zitko and J.Bonca

FMF, University of Ljubljana, and J. Stefan Institute, Ljubljana, Slovenia

(D ated: M arch 22, 2024)

W e develop a non-perturbative num ericalm ethod to study tunneling of a single electron through an Aharonov-Bohm ring where several strongly interacting electrons are bound. Inelastic processes and spin- ip scattering are taken into account. The method is applied to study microscopic mechanisms of dephasing in a non-trivialmodel. We show that electron-electron interactions described by the Hubbard Hamiltonian lead to strong dephasing: the transmission probability at ux

= is high even at sm all interaction strength. In addition to inelastic scattering, we identify two energy conserving m echanisms of dephasing: sym m etry-changing and spin-ip scattering. The m any-electron state on the ring determ ines which of these m echanisms s will be at play: transm itted current can occur either in elastic or inelastic channels, with or without changing the spin of the scattering electron.

PACS num bers: 73.63.-b 72.10.-d 71.10.-w

I. IN TRODUCTION

Advances in the sem iconductor technology made it possible to study quantum interference e ects in m esoscopic system s where the wave nature of electrons plays an essential role. Particularly noteworthy are the studies of the A haronov-Bohm (AB) oscillations in mesoscopic rings^{1,2,3}. The analysis of results in terms of the singleelectron picture turned out to be inadequate to describe the totality of phenom ena. Inelastic scattering of electrons is believed to be the predom inant mechanism responsible for the loss of the phase coherence in such experiments and the suppression of the h=e oscillations. W hen an electron interacts with optical phonons, the dephasing only occurs through inelastic processes⁴. At low tem peratures the phonon degrees of freedom freeze out, therefore other mechanisms for dephasing should be taken into account. M easurem ents of the dephasing time saturation at low temperatures^{5,6} show that zeropoint uctuations of the electrom agnetic environm ent⁷ could play a role in explaining this anom alous behavior. It is nevertheless believed, that at low tem peratures the electron-electron interaction is the dom inant mechanism for dephasing^{8,9}. Further support for the importance of electron correlations at very low tem peratures com es from recent m easurem ents of anom alous tem perature dependence of the dephasing time in mesoscopic K ondo w ires¹⁰ w here non-Ferm i-liquid behavior has been found below the K ondo tem perature.

The AB geom etries have been theoretically studied using self-consistent m ean- eld approximations that break down for degenerate levels, which physically happens at very low temperatures^{11,12,13}. The m ean-eld approximation does not describe transitions in which the symmetry of the many-electron wavefunction of correlated bound electrons changes and it is thus inadequate to study dephasing. Keldysh type G reen's functions and numerical renormalisation group techniques^{14,15} or equation of motion method¹⁶ have been applied to AB systems, where calculations were limited to interacting quantum dot with two levels coupled to reservoirs. Particular attention was devoted to the appearance of the K ondo physics induced by changing the magnetic ux, how ever no spin- ip induced dephasing has been investigated by these methods. A study of a C oulom b blockade regim e was recently done by X iong and X iong¹⁷ with a method, sim ilar to the one proposed in the present work. Their H am iltonian, how ever, m aps on a non-interacting model in the limit when the coupling to the leads is zero. Furthermore, they have only investigated spinless ferm ions and neglected inelastic scattering channels. T ransmission of two interacting electrons was recently studied on the basis of continuous two-particle H am iltonian where an enhancem ent of transmission with increasing interaction strength was found¹⁸.

To shed some new light on the problem of dephasing in electron tunneling experiments, there is obviously a dem and for a capable method that would treat the problem of the scattering of an electron through a nite region where electron-electron (e-e) interactions would be exactly taken into account. Such a method should be based on the use of exact correlated many-electron wavefunctions.

In this P aper we propose a method that treats the e-e interactions by direct diagonalisation of the many-body H am iltonian using iterative (Lanczos) technique. The method naturally takes into account spin- ip processes, so it can predict the ratio of spin- ip over norm al scattering processes. This makes the technique interesting for calculating spin-polarized transport¹⁹ in the eld of spintronics.

We apply the method to study single-electron transm ission through an Aharonov-Bohm (AB) ring with e-e interactions. As it is widely known, an electron perfectly re ects from an AB ring when the ux penetrating the ring is such that the phases gained by the electron traveling through the lower or the upper arm of the AB ring canceleach other (=). Such re ection occurs for any energy of the incident electron. This remains true even when there are electrons bound on the AB ring, as long as

the system remains non-interacting. The main purpose of our investigation is in the in uence of the nite Coulomb repulsion on the transmission of the electron in the case described above. W e choose the Hubbard model to describe the AB ring. The Hubbard model is the simplest yet most im portant nontrivial prototype model for correlated electrons in the solid state. As we will show, nite Coulom b interaction in certain cases leads to nite transm ission of the incident electron, despite the fact that the total wavefunction for the scattering electron and electronsbound on the AB ring preserves full quantum coherence. W e will therefore refer to the processes that lead to nite transmission in the case when = as dephasing processes since they clearly lead to dim inished AB oscillations observed in experim ents. W e show that dephasing can occur either by a) inelastic processes where the tunneling electron excites bound electrons on the ring or by b) elastic (in regard to energy) processes, where the tunneling electron changes the symmetry or the spin of the degenerate m any-electron w avefunction. No exchange of energy is required in the latter case^{19,20,21,22}: dephasing occurs because the tunneling electron leaves a trace on its \environm ent", which consists of bound electrons.

II. M ETHOD

The proposed method is based on the multichannel scattering technique that was developed for studying the tunneling of a single electron in the presence of scattering by phonons^{23,24}. Since its introduction, it has been successfully applied to a variety of problem s where a single electron is coupled to phonon modes^{4,25,26,27,28,29,30,31}. It was even incorporated into Landauer theory where the in uence of electron-phonon scattering on the non-equilibrium electron distribution has been investigated³². We now generalise this method to study many-electron problem s.

A. M odel H am iltonian

W hile the m ethod can be applied to m ore general situations and arbitrary geom etries of the interaction region, we choose for simplicity a particular physical system which will also serve as a toy-m odel for the study of the e-e interaction induced dephasing. We thus consider an AB ring coupled to two ideal one-dimensional leads, see Fig. 1. The ring is described by a Hubbardtype H am iltonian

$$H_{ring} = \begin{cases} X \\ G_{j}, \ ^{Y}C_{j}, \ te^{i \ j} C_{j+1}, \ ^{Y}C_{j}, + h.c. \end{cases}$$

$$j; \qquad X \\ + U \qquad C_{j;"} \ ^{Y}C_{j;"} C_{j;\#} \ ^{Y}C_{j;\#}$$
(1)

The operator c_j ; ^y creates an electron with spin at site j and we make a form alidenti cation c_7 ; ^y = c_1 ; ^y.

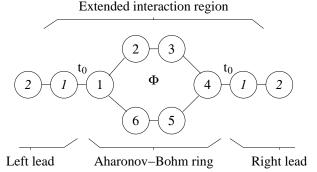


FIG.1: A haronov-Bohm ring. M agnetic ux penetrates the center of the ring.

The phases j describe phase changes due to m agnetic ux penetrating the ring. We chose a gauge in which we ascribe the total phase change due to m agnetic eld ux, $= 2 \quad M = 0$, (where M is the m agnet eld ux and 0 = h = e is the ux quantum) to a single element, e.g. $1 = and \quad j = 0, j \in 1$.

The leads are described by a tight-binding H am iltonian

$$H_{lead} = t_{lead} a_{i+1}; {}^{y}a_{i}; + h.c.$$
(2)

$$\begin{array}{c} X\\ t_{\text{lead}} \quad b_{i+1}, \ {}^{y}b_{i}, \ + \ h.c. \qquad (3)\\ \vdots \end{array}$$

The operator $a_{i;}$ ^y creates an electron with spin at site i on the left lead, while the operator $b_{i;}$ ^y does the same on the right lead. The ring is coupled to the electrodes with coupling constants t_0 :

$$H_{c} = t_{0}^{X} a_{1}; {}^{y}c_{1}; + h.c. t_{0}^{X} b_{1}; {}^{y}c_{4}; + h.c.$$
(4)

The coupling constant t_0 need not be small: the method applies equally well for strong coupling between the interaction region and the leads.

B. Correlated m any-electron states and exact diagonalisation

The transmittivity can be meaningfully dened in many-electron scattering problem only if one single electron leaves the scattering region. For this reason, we restrict the energy of the incoming electron to be below the ionisation threshold. Our approximation then consists of taking into account only those many-electron states in which at most one (scattering) electron is located outside the ring. Before the impact of the electron (which, for convenience, will be chosen to have spin up), there are $n = n_* + n_{\#}$ other electrons bound on the AB ring. We truncate allm any-body states, where additional electrons hop from the interacting region to the lead. When

physical parameters of the system, e.g. (;t;U), are chosen in such a way that these n electrons are bound in the interacting region, the approximation is equivalent to neglecting the exponentially decaying tails of the n-electron wavefunction in the leads.

B efore the scattering, the bound electrons are therefore in one of the n-particle eigenstates of the Ham iltonian H_{ring}, Eq. (1). We denote these states by j_{i} and their energies by i_{i} . The superscript index " denotes that the electron in the lead has spin up.

W hen the incoming electron enters the ring, the system is in a superposition of the n + 1-particle states which we denote by j_i i. These states are not necessarily eigenstates of H_{ring} . A fler the scattering there is a single electron in the leads, while the ring is in a superposition of the n-particle eigenstates of H_{ring} . These states are the $j_i^{"}$ i states and (if the spin of the scattering electron can be ipped) the n-electron eigenstates with $n_r + 1$ spin-up electrons and n_{if} 1 spin-down electrons. These spin-ipped states are labeled by $i_r^{"}$

ipped states are labeled by j_i^{\dagger} i and their energies by j_i^{\dagger} . Because all the possible states of the ring after scattering are orthogonal to each other, the outgoing channels are well de ned and the current is conserved.

We calculate the eigenstates j_i i using exact diagonalisation of the H am itonian H_{ring} in the suitable region of the many-particle H ilbert space, taking into account that the H ubbard H am iltonian is invariant with respect to rotations in the spin space. The diagonalisation is therefore performed in the constant (n;S_z) space, where S_z is the conserved component of the total spin in the z direction. The method can be applied to H am iltonians that don't conserve S_z at the expense of signi cantly m ore time consum ing num erical calculations.

At zero temperature, the electron scatters on the ground state of the n-particle state in the ring, $j_0^{"}i$. During the scattering the electron can bose energy by exciting the bound electrons into one of the excited $j_i^{"}i$ states. The probability of such transitions is a rapidly decreasing function of the energy loss, therefore only a small number of the scattering channels (states $j_i^{"}i$) has to be considered. This observation is essential for num erical perform ance of the method: we can e ciently calculate the states from the bottom of the spectrum of the matrix representations of H in suitable (n;S_z) subspaces using the iterative Lanczos technique. We have used the implicitly restarted Lanczos method, as implemented in ARPACK package³³. The eigenvalues and eigenvectors were computed to machine precision.

By taking into account only the allowed states, the wave-function that describes the scattering of one electron on the AB ring is given by

$$ji = \begin{cases} X^{i} X & X^{i} X \\ d_{i;j}^{L}, a_{i;} y_{j}i + d_{i;j}^{R}, b_{i;} y_{j}i \\ & d_{i;j}^{i=1}, j; \\ & e_{jjj}i; \end{cases}$$
(5)

where $d_{i_{j}j_{j}}^{\rm L}$, $d_{i_{j}j_{j}}^{\rm R}$ and e_{k} are the coe cients to be determined.

C. Reduction to a sparse system of linear equations

W e consider a steady-state scattering described by the the Schrodinger equation

$$H j i = E j i$$
 (6)

with $H = H_{ring} + H_{lead} + H_{c}$. Strictly speaking, this equation cannot be solved in the restricted space, spanned on the j_i i and j_i i states, because applying the H am iltonian to the wave-function ansatz takes us out of this space by generating term s where m ore than one electron can be found outside the scattering region. Om ission of these terms represents the m ain approximation used in ourm ethod. This approximation leads to an error which is not signi cant for suitably chosen m odel parameters (see below).

O perating on the equation (6) from the left with h $_1j$ we obtain

where b's denote scalar products

$$\begin{array}{l} b_{l_{j}j_{j}}^{L} &= h_{1}j_{l_{1}}, \ ^{y}j_{j}i_{j}i_{j}\\ b_{l_{j}j_{j}}^{R} &= h_{1}j_{2}, \ ^{y}j_{j}i_{j}i_{j} \end{array}$$
(8)

while $h_{1;k} = h_1 H_{ring} j_k i$ are the matrix elements of Ham iltonian H_{ring} in the n + 1 electron subspace.

By operating with h $_{j}$ ja₁; from the left we get

$$t_{\text{lead}} d_{2;j;}^{\text{L}}$$
 $t_{0} \qquad \begin{pmatrix} X \\ b_{k;j;}^{\text{L}} \end{pmatrix} e_{k} + {}_{j} d_{1;j;}^{\text{L}} = E d_{1;j;}^{\text{L}}$: (9)

D. Pruning the leads

In an open outgoing channel (j;) a plane wave can propagate, so that $d_{2;j;}^L = \exp(ik_{j;})d_{1;j;}^L$. By energy conservation the wave num ber $k_{j;}$ is obtained from

$$_{0} 2t_{lead} \cos(K) = _{j} 2t_{lead} \cos(k_{j};):$$
 (10)

The energy $_0$ is the initial energy of the n-electron bound state on the ring, K is the wave number of the incoming electron, and $_j$ is the nalenergy of the bound electrons. Equation (9) can thus be written as

$$d_{1;j;}^{L} = \frac{t_{0}^{P} (d_{k;j;}^{L}) e_{k}}{E (t_{k}^{L}) + t_{kead} \exp(ik_{j;})}$$
(11)

Similar equation can be obtained for exponentially decaying (closed) outgoing channels that we also take into account (up to some cut-o energy, above which the inclusion of further closed channels does not change the results). These are dened through the relation $d_{2,j}^{L}$ = exp($_{j}$, $)d_{1,j}^{L}$ and

$$_{0} \quad 2t_{lead}\cos(K) = _{j} \quad 2t_{lead}\cosh(k_{j};): \quad (12)$$

Equation (9) can in this case be written as

$$d_{1;j;}^{L} = \frac{t_{0}^{P} (b_{k;j;}^{L}) e_{k}}{E (j + t_{lead} exp(j))} e_{k};$$
(13)

In the incoming channelwe have both the incoming and outgoing waves, $d_{m \ ;0;"}^{L} = \exp(iK m) + rexp(iK m)$. We obtain $d_{2;0;"}^{L} = \exp(iK) d_{1;0;"}^{L} + \exp(2iK)$ 1. The equation for the incoming channel thus contains an additional inhom ogeneous term exp(2iK) 1 and Equation (9) for the incoming channel is

$$d_{1;0;"}^{L} = \frac{t_{0}^{P} (b_{k;0;"}^{L}) e_{k} t_{lead} [exp(2iK)]}{E_{0} + t_{lead} exp(iK)}$$
(14)

U sing Eqs. (11), (13), (14), and sim ilar equations for the right lead, both leads can be rem oved (pruned) from the problem 24 .

E quations (7), (11) and equivalent equations for other outgoing channels form a system of linear equations for unknowns $d_{1;j;}^L$, $d_{1;j;}^R$, and e_j . This sparse system is solved for di erent energies of the incoming electron using the SuperLU library³⁴.

The partial transmittivity through channel (j;) is given by

$$T_{j}; (E) = \frac{\sin(k_{j};)}{\sin(K)} \dot{p}_{1,j}^{R}; \dot{f}:$$
(15)

Since the method is based on exact solution of manyelectron problem, we can compute transmission at arbitrarily large values of U.

E. Extended interaction region

R esults can be improved by extending the interaction region which is solved exactly by the Lanczos m ethod by adding additional sites from the leads. This procedure takes into account the decaying tails of bound electron w avefunctions in the leads at the expense of increasing the computational H ilbert space. The error due to the om ission of the term s corresponding to a second electron jumping out of the original interaction region [see discussion following Eq. (6)] is exponentially reduced with the inclusion of each additional site from the leads.

These in provem entsm ainly lead to energy shifts of the resonance peaks while the general characteristics of the spectra rem ain unchanged. In principle, the region could be extended until the desired convergence is achieved. In

our calculations the interacting region consisted of the ring and one additional site from each lead, see Fig. 1. In fact, we had to take into account the site on the left electrode in order to ensure that the incident electron spreads into two partial waves that propagate through both arms of the ring. The additional site on the right electrode is required so that the partial waves can interfere, which leads to the Aharonov-Bohm e ect. The inclusion of these two sites was therefore essential in our studies of the dephasing mechanism s.

In cases where the ground state of the interaction region was degenerate, we averaged the transm ittivity spectra over all the degenerate states. The variational space taken into account in our calculation was equivalent to a H ubbard m odel on 8 sites with no translational sym m etry.

The largest problem that could be e ectively solved has 3 bound electrons with spin up and 4 electrons with spin down. In this case there are 8000 states j_i and

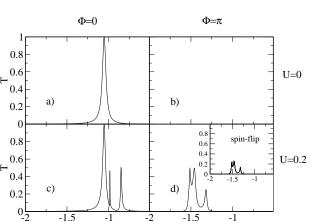
5000 j_ii states. We kept 200 lowest lying j_ii states to de ne our scattering channels (diagonalization took 3 m inutes of a m odest personal com puter). Solving the sparse system of com plex linear equations for a range of the incom ing electron energies took 200 m inutes for 237 data points (or about a m inute per data point on the average). This step is the m ost com putationally dem anding part of our technique. This is the m ain reason why we lim ited our calculations to 8 site m odels, even though the Lanczos m ethod easily handles m uch larger lattices.

III. RESULTS -ONE BOUND ELECTRON

We now investigate the e ect of interactions on an electron as it tunnels through the ring. The incoming electron has spin up and there is one bound electron with spin down inside the ring. The on-site energies are = $4.5t_{\text{lead}}$, the overlap integrals are t = $3t_{\text{lead}}$, and we set $t_{\text{lead}} = 1$.

First we consider the non-interacting case. In the absence of the magnetic eld the transm ission reaches unity at the resonance, Fig. 2a. The electron is fully rejected at any incident energy when the magnetic ux is =, Fig. 2b. This is the usual A haronov-B ohm elect.

We now turn on the interaction. At = 0 we still see a unity peak at the energy of the single-electron resonance, followed by smaller satellite peaks caused by the interaction, Fig. 2c. At = , when in the absence of U the electron is fully relected, we obtain very high transmission probability despite relatively small U = 0.2, Fig. 2d. In the largest peak the transmission approaches the value T = 1=2. Since the incoming electron and the bound electron are not entangled, their total spin is not well de ned, therefore the total wavefunction is a superposition of a singlet and a triplet state with equal am plitudes: J'#i = 1 = 2 ($\beta = 1; S_z = 0i + \beta = 0; S_z = 0i$). The triplet scattering has zero transmission probability at = since in the Hubbard model only singlet elec-



E

FIG.2: Transm ission probability as a function of the incident electron energy for one electron with spin down bound on the ring. The incom ing electron had spin up. The coupling to the lead is $t_0 = 0.4$. In all cases transm ission is purely elastic.

E

trons interact. The singlet scattering, however, reaches the unitary lim it at the main resonance peak. A veraging over both contributions, we indeed get T = 1=2.

The spin- ip scattering part of the transm ission probability is shown in the inset in Fig.2d. The spin- ip and norm all scattering contribute equally to the total transm ission probability. Both are purely elastic with respect to energy changes.

A. Lead decoupling at = and scattering m echanism s at non-zero U

To gain more insight in the mechanism of non-zero electron tunneling probability, we present a simple physical picture of electron tunneling for the case of = . We rst transform the A-B ring Hamiltonian (1) from the basis of localized states to a basis in k-space. For more generality, we can now assume that the ring consists of an arbitrary even numberm of sites, which we now num -

ber from 0 to m 1, so that the site 0 is coupled to the left electrode, while the site m = 2 is coupled to the right electrode.

The non-interacting part of the Ham iltonian (1) is diagonal in the plane-wave basis,

$$d_{n}; = \frac{1}{m} \prod_{j=1}^{X^{n}} e^{ijk_{n}} c_{j};$$
 (16)

with wave numbers k_n given by the periodic boundary condition exp(ik_nm) = 1, or k_n = 2 n=m, where n = 0; 1;::; m=2 1;m=2. The corresponding eigenvalues are

$$E_n = 2t\cos(k_n = m)$$
 (17)

W hen = , all the non-interacting eigenstates are twofold degenerate since $\cos(k_n - \frac{1}{m}) = \cos(k_1 - n - \frac{1}{m})$. The complete orthonormal set of states is therefore com – posed of m =2 pairs of states with wave-num bers k_n and $k_{1 - n}$ for n ranging from 1 to m =2. For each pair we can form two linear combinations of states:

$$a_{L,n}; = \frac{p}{\frac{1}{2}} (d_{n}; + d_{1,n};)$$

$$= \frac{1}{p} \frac{1}{2m} X e^{ik_{n}j} + e^{ik_{n}j} e^{\frac{i2}{m}} C_{j}; ;$$

$$a_{R,n}; = \frac{p}{\frac{1}{2}} (d_{n}; d_{1,n};)$$

$$= \frac{p}{2m} X e^{ik_{n}j} e^{ik_{n}j} e^{\frac{i2}{m}} C_{j}; ;$$
(18)

It is easy to see that the coe cient of $c_{m=2}$; in the expression for $a_{L,n}$; is zero and likewise for the coe cient of c_0 ; in the expression for $a_{R,m}$; . This means that the eigenstate denoted by L is coupled only to the left electrode, while eigenstate R is coupled only to the right electrode, see F ig. 3. In the non-interacting case the incoming electron can only tunnel from the left electrode to an L state. This state is decoupled from the right electrode and since there is no term in the H am iltonian, that would allow transitions from L to R state, the electron is fully relected.

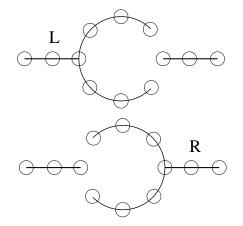


FIG.3:At = , one can rotate each pair of the degenerate eigenstates in such a way that one of them couples only to the left electrode and the other to the right electrode. In absence of interactions both electrodes are electroly decoupled.

There are therefore two equivalent physical descriptions of zero transm ittivity of an AB ring. One can either consider it as a destructive interference of partial electron waves that travel in the upper and lower arm of the ring, or as an elective decoupling of both electrodes due to a topological phase shift.

W e will now write the interacting part of the H am iltonian in the new basis and search for processes that are responsible for the nonzero transm ission. From Eqs. (16) and (18) we can express c_i ; as

$$c_{j;} = \frac{2e^{i(\frac{j}{m})}}{\frac{p}{2m}} \sum_{n=1}^{\frac{R}{2}} \cos(k_{n} j)a_{L;n;} + \sin(k_{n} j)a_{R;n;} :$$
(19)

where we have introduced shifted wave num bers

$$\tilde{K}_n = \frac{2}{m} n \frac{1}{2}$$
 : (20)

The particle number operator can then be expressed as

$$c_{j;}^{y} c_{j;} = \frac{2}{m} \sum_{p,q}^{X} \cos(\mathcal{K}_{p}j) \cos(\mathcal{K}_{q}j) a_{L,p;}^{y} a_{L,q;} + \sin(\mathcal{K}_{p}j) \sin(\mathcal{K}_{q}j) a_{R,p;}^{y} a_{R,q;} (21) + \cos(\mathcal{K}_{p}j) \sin(\mathcal{K}_{q}j) a_{L,p}^{y} a_{R,q;} + \sin(\mathcal{K}_{p}j) \cos(\mathcal{K}_{q}j) a_{R,p}^{y} a_{R,q;} :$$

 $8 \sin(a) \sin(b) \sin(c) \sin(d) =$

$$\cos(a \ b \ c \ d) + \cos(a + b \ c \ d)$$

+ $\cos(a \ b + c \ d) \ \cos(a + b + c \ d)$ (22)
+ $\cos(a \ b \ c + d) \ \cos(a + b \ c + d)$
 $\cos(a \ b + c + d) + \cos(a + b \ c + d)$:

W e note that reduction form ulas for an even number of sine and cosine functions consist of a sum of cosine functions, while the reduction form ulas for an odd number of sine and cosine functions consist of a sum of sine functions. This fact is important to understand the selection rules that lead to dephasing.

The arguments of functions on the right hand sides of the reduction formulas are sums of the form $\frac{2 j}{m} p \frac{1}{2} q \frac{1}{2} r \frac{1}{2} s \frac{1}{2}$, i.e. of form $\frac{2 j r}{m}$, where t is an integer. When the summation over site index j is performed most of the terms will drop, since

$$\frac{1}{m} \sum_{j=1}^{X^{n}} \cos \frac{2 t}{m} j = t_{;0};$$

$$\frac{1}{m} \sum_{j=1}^{X^{n}} \sin \frac{2 t}{m} j = 0;$$
(23)

All interaction terms with a coe cient that after trigonom etric reduction involves a sine function will therefore vanish. Such vanishing terms come from products of an odd number of trigonom etric functions of each kind, therefore they are of the form such as

$$a_{R}^{y}{}_{,p;"}a_{L}{}_{;q;"}a_{L}^{y}{}_{;r;\#}a_{L}{}_{;s;\#}$$
: (24)

Such term swould allow (for p = q, r = s) transitions of the tunneling electron from state L to R without changing the bound electron state (i.e. without leaving any imprint on the environment). Such transitions would clearly be in contradiction with our understanding of the dephasing in the A-B rings.

The terms with four sine and with four cosine functions are of little in portance for our purposes. They describe interlevel repulsion and interlevel transitions without changes of the L/R character of the electron states and therefore do not lead to a nite transmission. We will focus instead on terms with two sine and two cosine functions. They are of three kinds. The rst one consists of term s of the form

$$a_{R,p;"}^{\gamma}a_{L;q;"}a_{L;r;\#}^{\gamma}a_{R;s;\#}:$$
 (25)

These terms describe what we call symmetry-changing transitions: the tunneling electron (with spin up) in the L state jumps to a R state, while a bound electron undergoes a transition from R to L state. Such a transition can either be elastic (with respect to the energy of the tunneling electron) if p = q, r = s (Fig. 4), or inelastic (Fig. 5).

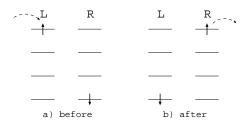


FIG.4: Transm ission due to elastic symmetry-changing scattering.

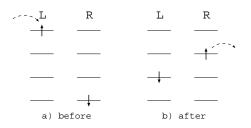


FIG. 5: Transm ission due to inelastic symmetry-changing scattering.

The second kind of terms is of the form

$$a_{L,p;"}^{\gamma}a_{L,q;"}a_{R,r;\#}^{\gamma}a_{R,s;\#}:$$
 (26)

These terms correspond to spin- ip transitions: the tunneling electron with spin-up in the L;q state makes a transition to a low er laying state L;p state, while a bound electron undergoes a transition from the R;s to the R;r state, Fig. 6. Transition can again be either elastic (with respect to energy) for p = q, r = s (Fig. 6), or inelastic (Fig. 7).

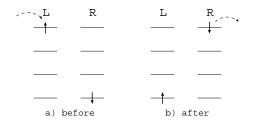


FIG.6: Transm ission due to elastic spin-ip scattering.

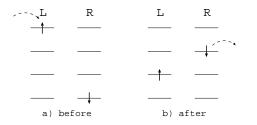


FIG. 7: Transm ission due to inelastic spin- ip scattering.

Finally, term s of the form

$$a_{R,p;"}^{y} a_{L;q;"}^{y} a_{R;r;\#}^{y} a_{L;s;\#}$$
 (27)

can correspond either to symmetry-changing (Fig. 8) or to spin-ip transitions (Fig. 9), depending on the p;q;r;s quantum numbers.

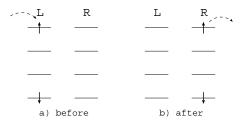


FIG.8: Transm ission due to elastic sym m etry-changing scattering (of the second kind).

B. Scattering of a wave packet

To illustrate more in detail our results presented in the previous subsection, we present here numerically exact calculation of scattering of an incoming electron (described as a wave packet with a given nite energy width) on the electron with the opposite spin, bound on the A haronov-Bohm ring. Since we are dealing with a sim – ple case of only two electrons, this problem can be solved numerically exactly by direct integration of the two-body Schrodinger equation ihdj i=dt = H j i. We take into consideration a su ciently high number of chain sites, so that the positional spread of the wave packet is sm aller than the length of the left and the right lead. We chose N = 200 sites, where the 6-site A haronov-Bohm ring occupies positions ranging from 101 to 106.

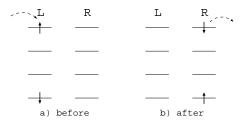


FIG .9: Transm ission due to elastic spin- ip scattering (of the second kind).

We construct the wavefunction at the initial time as $j i = \bigvee_{\text{"packet}}^{y} \bigvee_{\text{#bound}}^{y}$ Di. The operator $\bigvee_{\text{#bound}}^{y}$ creates an electron with spin down in the bound eigenstate of the Aharonov-Bohm ring. We calculated this state using direct diagonalisation. The operator $\bigvee_{\text{"packet}}^{y}$ is

$$y_{\text{packet}} = C \sum_{k}^{X} \exp \left(\frac{(k - k_0)^2}{2^2}\right) \exp (-ikN_{\text{center}})c_{\pi_k}^y$$
(28)

where $c_{n_k}^y = 1 = \frac{p - P}{N} \sum_{j=1}^{N} \exp(ikj) c_{n_j}^y$ and C is a norm alization constant. This operator creates an electron with spin up in a wave packet centered at site N _{center} which has the average wave number k_0 and a spread of in the k-space. We choose $k_0 = -2$ to place the wave packet in the middle of the energy band of the leads with the group velocity $v = 0 \in E = 0 \text{ (k } (k = k_0) = t = 1$. We set = 0.13 and N _{center} = 50.

The equation of motion was then integrated using Bulirsch-Stoer method, which gives highly accurate results for this type of problem s. The accuracy and stability can be conveniently estim ated by monitoring the deviation from the proper norm alization of the wave-function. U sing the Bulirsch-Stoer method the norm alization differs from 1 at the eighth decim alplace after the scattering.

We set the parameters to = 3:0, t = $p_{\overline{3}}$, t₀ = 0:6, t_{lead} = 1. For the non-interacting system the transm ittivity at = is 0 for all electron energies, while the transm ittivity of an interacting system with U = 1 is shown in Fig. 10. The location and the spread of the energies of the wavepacket are represented in the gure by a two-sided arrow.

The electron density before and after the scattering at = is shown in Fig. 11 for the non-interacting case and in Fig. 12 for the interacting case³⁷. For U = 0, the wave-packet is perfectly re ected, as expected. For U = 1 the wave-packet is partially transmitted through the scattering region. In fact, the expectation value to nd an electron in the second electrode, P_R , corresponds to the following average:

$$P_R = dkT((k))j_{\text{market}}^{Y}(k;t=0)f;$$
 (29)

where the transm ission T is calculated using the m ethod from section II and is presented in Fig. 10. This equation

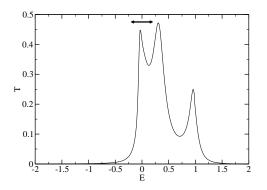


FIG.10: Transm ission probability as a function of the incident electron energy for one electron with spin down bound on the ring.

connects and thus validates the two distinct m ethods. It is furtherm ore worth stressing, that the probability of nding electrons with either orientation of spin in the second electrode is equal, see F ig. 13. This can be explained as follows: nite transm ission is a direct consequence of interaction U which in the case of two electrons acts only on the singlet part of the wavefunction. The triplet part does not feel U due to the on-site nature of the interaction. Transm ission therefore occurs only through the singlet channel.

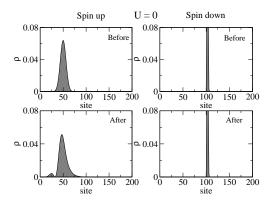


FIG. 11: E lectron density before and after the scattering of the wave-packet on an Aharonov-Bohm ring at = : noninteracting case. Note that the vertical scale is the same for both spin projections: the scale was chosen so that the wavepacket is clearly visible.

C. A haronov-Bohm oscillations

A haronov-B ohm e ect is experimentally observed as magnetic ux dependent oscillations of the electric current through a mesoscopic ring structure¹. From cal-

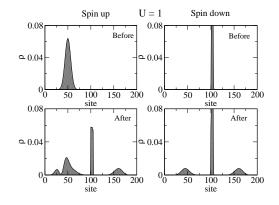


FIG. 12: E lectron density before and after the scattering of the wave-packet on A haronov-Bohm ring at = : interact-ing case.

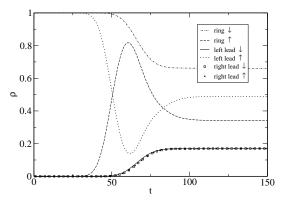


FIG.13: T in e dependence (for interacting case) of the probability to nd an electron with given spin projection either in the ring, in the left electrode or in the right electrode.

culated T (E) spectra we could estimate the zero-bias conductance as $G = G_0 T (E_F)$, where $G_0 = 2e^2 = h$ is the conductance quantum and E_F is the common Fermi level of both leads. In our minimal model with a discrete number of resonance states in the ring, the energy shifts of the peaks when the ux is changed (see Eq. (17)) lead to pronounced conductance variations not necessarily connected to the Aharonov-Bohm e ect itself. This is a direct consequence of using a small discrete num – ber of sites. It is therefore more revealing to observe the variations of the integral of transmittivity over the whole energy band, T (E) dE. This quantity is relatively insensitive to energy shifts of the peaks, while it should clearly show A-B oscillations which a ect the height of all of the peaks.

In Fig. 14 we present this integral as a function of for a number of increasing interaction strengths U = 0;0:1;:::;1:0. The amplitude of A-B oscillations noticeably decreases as the interaction grows stronger. Fig-

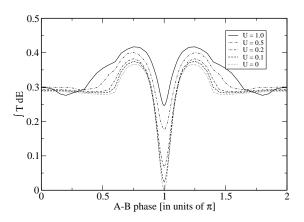


FIG.14: The ux dependence of integrated transmission probability for di erent interaction strengths. The coupling to the leads is $t_0 = 0.6$, all other parameters are as before.

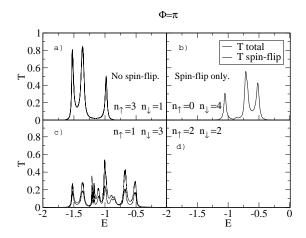


FIG.15: Transm ission probability as a function of the incident electron energy for n_{*} (n_{*}) electrons with spin up (down). Parameters are = 4:5, t = $\frac{1}{3}$, U = 1:0, t₀ = 0:3 and t_{lead} = 1.

ure 14 also shows, that the integral transm ittivity is essentially interaction independent around zero ux, = 0. A similar insensitivity of the transm ittivity sum-rule has been discovered in the case of tunneling in the presence of electron-phonon coupling^{4,35,36}. This insensitivity breaks down at larger U.

IV. MANY BOUND ELECTRONS ON THE RING

We now consider several interacting (U = 1) bound electrons on the ring. All presented cases are calculated at the ux value = , unless otherwise speci ed. Spin of the incoming electron is up. We have limited the en-

ergy of the incident electron to a half of the bandwidth, i.e. E = [2;0], in order to avoid ionisation. Our main goal in this section is to investigate the circum stances, under which a scattering electron obtains a nite transm ission probability at = when scattering through the AB ring in the presence of m any bound electrons. W e show that in most cases C oulom b interaction leads to nite transmission. In our work we refer to processes which cause nite transmission as dephasing processes. To avoid confusion we point out once more that the total wavefunction describing a many-body state of the scattering electron and bound electrons preserves its full quantum coherence throughout the calculation. Our H am iltonian does not contain coupling to external degrees of freedom that would naturally lead to dephasing.

When the bound state on the ring consists of three electrons with spin up and one electron with spin down (Fig. 15a) no spin- ip scattering is possible because such processes turn out to be energetically in possible. The ground state is how ever fourfold degenerate and the turneling electron can get through the ring at nite U by changing the sym m etry of the m any-electron state on the ring. Since the ground state is degenerate, this process is purely elastic.

In the case of $n_{*} = 0$; $n_{\#} = 4$ (Fig. 15b) the ground state is non-degenerate, how ever the spin- ip processes are energetically allowed. We therefore obtain transm ission probability only in spin- ipped channels. Since in this case the ground state is not degenerate, the transm ission consists of purely inelastic processes.

In the case when the ground state is degenerate and the spin- ip processes are allowed, we expect dephasing to occur both with or without spin ip. Such is the case of $n_* = 1$; $n_{\#} = 3$, Fig. 15c. The transm ittivity without spin- ip is purely elastic, while the spin- ip processes are predom inantly elastic, with sm all contribution from inelastic channels.

Finally, for $n_* = 2$; $n_{\#} = 2$ electrons are fully rejected from the ring since there are no allowed scattering channels in the appropriate energy interval, Fig. 15d.

We nally show the in uence of large U = 15 on the case of $n_{*} = 2$; $n_{\#} = 2$, where at U = 1 transm ission rem ained zero in the whole intervalof incom ing electron energy due to widely spaced many-electron levels. At large U = 15 the energy di erence between the non-degenerate ground state and the rst excited state decreases in com parison with U = 1 case, as the states become com pressed in the lower Hubbard band. We changed the on-site energy to = 20 in order to keep the electrons bound on the ring. At = 0 there are several energies at which the electron can resonantly tunnel through the ring, Fig. 16a. At = , the electron can only tunnel inelastically. The energy di erence to the rst excited state in the n electron Hubbard band is approximately 1:4.We nd indeed that only the electrons that are more than 1:4 above the bottom of the energy band can tunnel, Fig. 16b. Such inelastic processes occur both without (Fig. 16c) or with spin-ip (Fig. 16d).

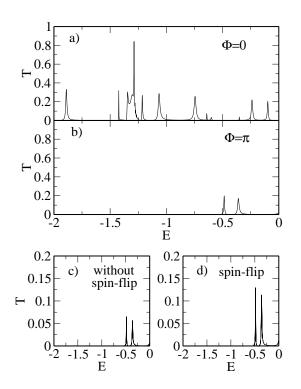


FIG.16: Transm ission probability as a function of incident electron energy for $n_* = 2$; $n_{\#} = 2$, U = 15 and = 20.

V. CONCLUSIONS

Using a simple model and a new numerical method we have investigated physics of single electron tunneling through the AB ring in the presence of correlated bound electrons. In particular we have focused on the the role of electron-electron interactions on dephasing. W hile the proposed m ethod clearly has som e lim itations (sm all interacting regions, inability to describe ionization processes, neglect of many-body e ects in the leads), it nevertheless allows to treat the strong-interaction problem exactly and to identify the two principalm icroscopic mechanisms which lead to the loss of phase coherence in quantum interference experiments. We showed that a particle can tunnel through AB ring at = elastically by a) changing the sym metry of the many-electron state which is possible in the case of degeneracy or b) by ipping the spin. Tunneling can also occur in the inelastic channel by exciting the many-electron state on the ring into an excited state with or without the spin- ip.

D epending on the num ber of bound electrons, their total spin, degeneracy of the ground state and available energy of the incom ing electron, the total transm ission can be com posed of partial transm issions caused by either one of the listed processes.

U sing the novelm ethod we have thus unraveled m icroscopic m echanism s based on electron-electron interaction that in a mesoscopic system contribute to a nite transm ission through the AB ring in the case of = . How – ever, since ourm ethod is based on sm all physical system s that can handle only a few lattice sites and interacting electrons we have no m eans at this stage to perform accurate calculation of the dephasing rate.

Even though all presented results are obtained on the basis of zero-tem perature calculations, the method can be generalised to nite temperatures with some additional num erical e ort. On the other hand, our results do not necessarily predict a nite dephasing rate at zero tem perature. Since we treat only a single electron in the leads we are completely neglecting the elects of manybody interactions spreading from the interacting region to the electrons in the leads. This spread form s the basis for the K ondo e ect. At tem peratures below the K ondo tem perature T_K , our approach therefore breaks down; in the K ondo regime the spins of the electrons from the interacting region couple into singlets with the electrons from the leads. This process prevents spin- ip scattering, which in our calculation represents one of the mechanisms for dephasing. K ondo coupling m ay also lift the degeneracy of the many-electron states in the interacting region and thus prevent transm ission through the elastic channel which leads to dephasing at zero temperature according to our ndings. O ther mechanisms leading to dephasing in our approach might as well be modied in this low-tem perature regime. We therefore conclude that despite the zero-tem perature form alism used in our m ethod, our calculations are relevant only at tem peratures higher than the K ondo tem perature T_K .

The m ethod can be applied to study otherm any-body e ects that are expected to be important in nanoscopic structures due to strong electron-electron and electronphonon coupling. A more general implementation of the presented m ethod is under way.

A cknow ledgm ents

W e gratefully acknow ledge SA. Trugm an, I. M artin, A.Ram sak, T.Rejec and J.H.Je erson for fruitful discussions. Authors also acknow ledge the support of the M inistry of Education, Science and Sport of Slovenia.

¹ R.Webb, S.Washburn, C.P.Umbach, and R.B.Laibowitz, Phys.Rev.Lett.54 (1985).

² G.Timp et al, Phys.Rev.Lett. 58 (1987).

³ E.Schuster, E.Buks, M.Heiblum, D.Mahalu, V.Uman-

sky, and H. Shtrikm an, Nature 385, 417 (1997).

- ⁴ K.Haule and J.Bonca, Phys.Rev.B 59, 13 087 (1999).
- ⁵ P.M ohanty, E.M.Q. Jariwala, and R.A.Webb, Phys. Rev.Lett. 78, 3366 (1997).
- ⁶ P.M ohanty and R.A.W ebb, Phys. Rev. B 55, R13452 (1997).
- ⁷ D.Golubev and A.D.Zaikin, Phys. Rev. Lett. 81, 1074 (1998).
- ⁸ A.E.Hansen, A.Kristensen, S.Pedersen, C.B.Sorensen, and P.Lindelof, Phys. Rev. B 64, 045324 (2001).
- ⁹ D.Golubev and A.D.Zaikin, Phys. Rev. B 59, 9195 (1999).
- ¹⁰ F.Schopfer, C.Bauerle, W.Rabaud, and L.Sam inadayar, Phys.Rev.Lett 90, 056801 (2003).
- ¹¹ G.Hackenbroich and H.A.W eidenmuller, Phys.Rev.Lett. 76,110 (1996).
- ¹² G.Hackenbroich and H.A.W eidenmuller, Phys.Rev.B 53,16379 (1996).
- ¹³ E.Buks, R.Schuster, M.Heiblum, D.Mahalu, V.Umansky, and H.Shtrikman, Phys. Rev. Lett. 77, 4664 (1996).
- ¹⁴ W .Hofstetter, J.Konig, and H.Schoeller, Phys.Rev.Lett. 87, 156803 (2001).
- ¹⁵ D.Boese, W.Hofstetter, and H.Schoeller, Phys.Rev.B 64, 5309 (2001).
- ¹⁶ B.R.Bulka and P.Stefanski, Phys. Rev. Lett. 86, 5128 (2001).
- 17 S.X iong and Y.X iong, Phys.Rev.Lett.83, 1407 (1999).
- ¹⁸ O.Entin-W ohlm an, A.Aharony, Y.Im ry, and Y.Levinson, Europhys.Lett. 50, 354 (2000).
- ¹⁹ S.K. Joshi, D. Sahoo, and A.M. Jayannavar, Phys. Rev. B 64 (2001).
- 20 A.Stem, Y.Aharonov, and Y.Im ry, Phys.Rev.A 41,

3436 (1990).

- ²¹ P.A.Mello, Y.Imry, and B.Shapiro, Phys. Rev. B 61, 16570 (2000).
- ²² J.Konig and Y.G efen, Phys. Rev. B 65, 045316 (2002).
- ²³ E.V. Anda et al, Braz. J. Phys. 24, 330 (1994).
- ²⁴ J. Bonca and S. A. Trugm an, Phys. Rev. Lett. 75, 2566 (1995).
- ²⁵ J. Bonca and S. A. Trugman, Phys. Rev. Lett. 79, 4874 (1997).
- ²⁶ H.Ness and A.J.Fisher, Phys.Rev.Lett.83, 4520 (1999).
- ²⁷ H.Ness, S.A.Shevlin, and A.J.Fisher, Phys.Rev.B 63, 125422 (2001).
- ²⁸ H.Ness and A.J.Fisher, Europhys.Lett., 57, 885 (2002).
- ²⁹ H. M. Pastawski, L. F. Torres, and E. Medina, Chem. Phys. 281, 257 (2002).
- ³⁰ H.Ness and A.J.Fisher, Chem. Phys. 281, 279 (2002).
- ³¹ L.E.F.F.Torres, H.M. Pastawski, and S.S.Makler, Phys.Rev.B 64, 193304 (2001).
- ³² E.G. Em berly and G.K irczenow, Phys. Rev. B 61, 5740 (2000).
- ³³ R.B. Lehoucq, D.C. Sorensen, and C. Yang, ARPACK Users' Guide: Solution of Large Scale Eigenvalue Problems with Implicitly Restarted A moldi M ethods (1997).
- ³⁴ J.W .D em m el, J.R .G ilbert, and X .S.Li, SuperLU Users' Guide (1999).
- ³⁵ N.W ingreen, K. Jacobsen, and J.W ilkins, Phys. Rev. Lett. 61, 1396 (1988).
- ³⁶ N.W ingreen, K. Jacobsen, and J.W ilkins, Phys. Rev. B 40, 11834 (1989).
- ³⁷ Animations of the scattering process are available upon request from the authors.